**ON Semiconductor** 

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# Onsemi

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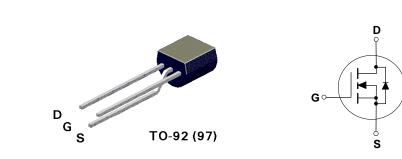
ON Semiconductor® BS270 N-Channel Enhancement Mode Field Effect Transistor

# **General Description**

These N-Channel enhancement mode field effect transistors are produced using ON Semiconductor's proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. They can be used in most applications requiring up to 500mA DC. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

### Features

- 400mA, 60V.  $R_{DS(ON)} = 2\Omega @ V_{GS} = 10V.$
- High density cell design for low R<sub>DS(ON)</sub>.
- Voltage controlled small signal switch.
- Rugged and reliable.
- High saturation current capability.



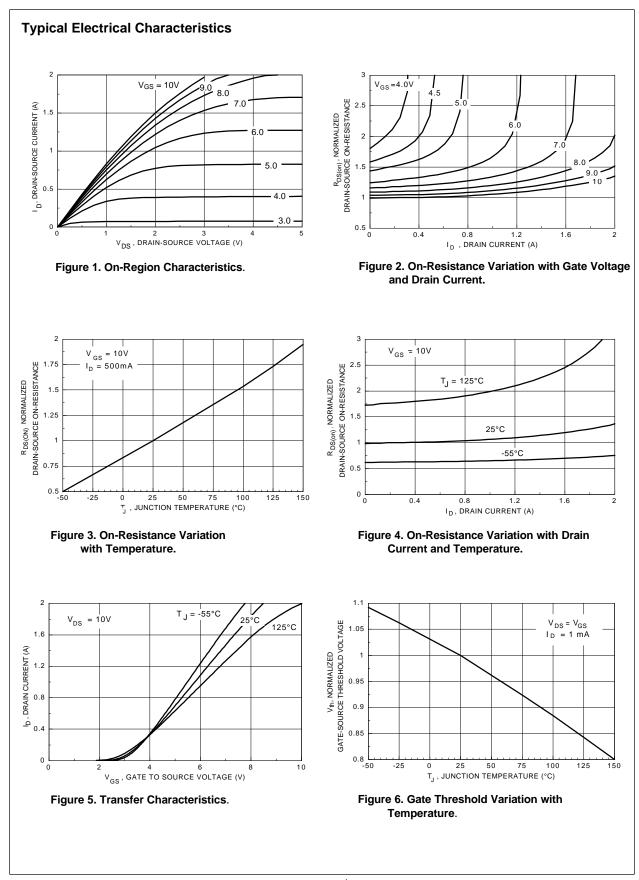
# **Absolute Maximum Ratings** $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	BS270	Units
V <sub>DSS</sub>	Drain-Source Voltage	60	V
$V_{\text{DGR}}$	Drain-Gate Voltage ( $R_{gs} \le 1M\Omega$ )	60	V
V <sub>GSS</sub>	Gate-Source Voltage - Continuous	±20	V
	- Non Repetitive (tp < 50µs)	±40	
I <sub>D</sub>	Drain Current - Continuous	400	mA
	- Pulsed	2000	
P <sub>D</sub>	Maximum Power Dissipation	625	mW
	Derate Above 25°C	5	mW/°C
T_,,T <sub>stg</sub>	Operating and Storage Temperature Range	-55 to 150	°C
TL	Maximum Lead Temperature for Soldering Purposes, 1/16" from Case for 10 Seconds	300	°C
THERMA	L CHARACTERISTICS		<u>.</u>
R <sub>eja</sub>	Thermal Resistacne, Junction-to-Ambient	200	°C/W

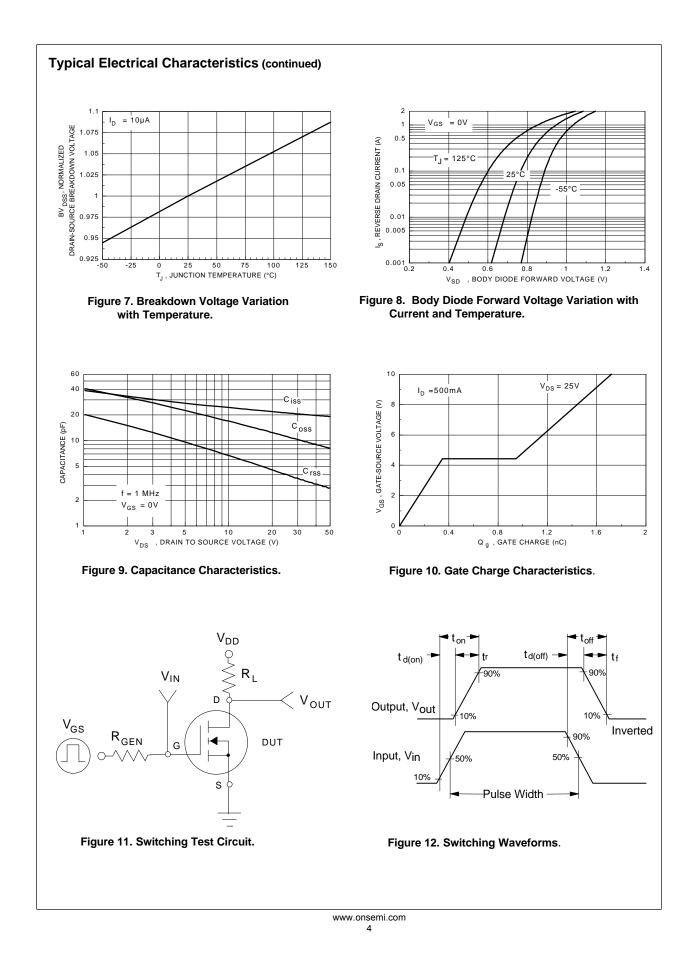
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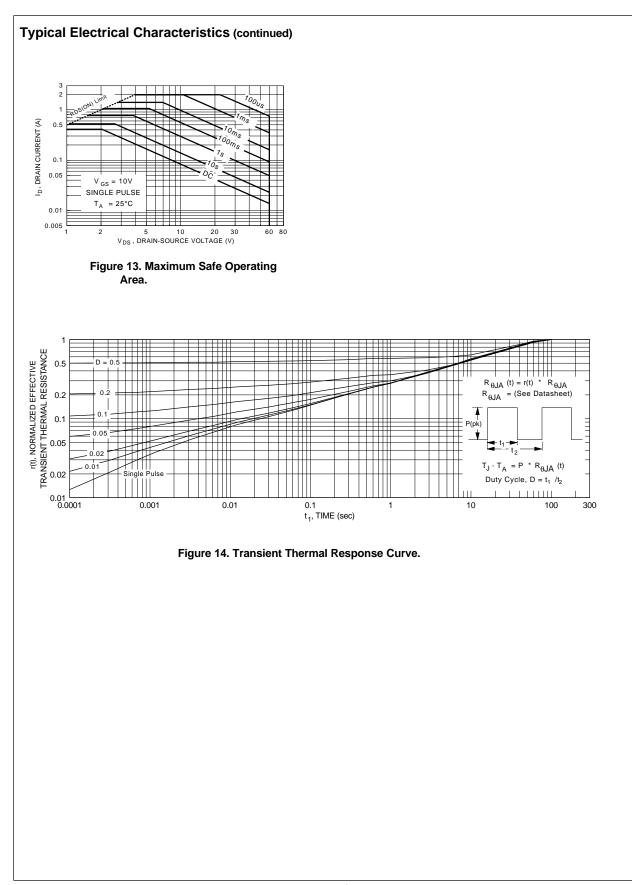
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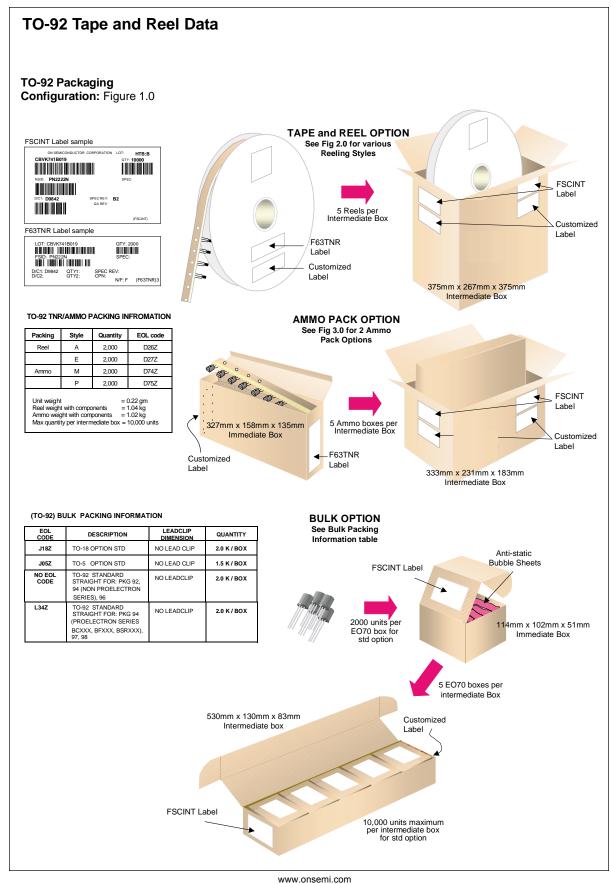
Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHA	RACTERISTICS	·					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{gs} = 0 V, I_{p} = 10 \mu A$		60			V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$				1	μA
			T <sub>J</sub> = 125°C			500	μA
GSSF	Gate - Body Leakage, Forward	$V_{gg} = 20 V, V_{Dg} = 0 V$	•			10	nA
GSSF	Gate - Body Leakage, Reverse	$V_{gg} = -20 \text{ V}, V_{Dg} = 0 \text{ V}$				-10	nA
	ACTERISTICS (Note 1)						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{ps} = V_{qs}, I_{p} = 250 \ \mu A$		1	2.1	2.5	V
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	V <sub>gs</sub> = 10 V, I <sub>p</sub> = 500 mA			1.2	2	Ω
			T_ = 125°C		2	3.5	
		V <sub>gs</sub> = 4.5 V, I <sub>p</sub> = 75 mA			1.8	3	
V <sub>DS(ON)</sub>	Drain-Source On-Voltage	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 500 \text{ mA}$			0.6	1 V	
		$V_{GS} = 4.5 \text{ V}, I_{D} = 75 \text{ mA}$			0.14	0.225	
I <sub>D(ON)</sub>	On-State Drain Current	$V_{gg} = 10 \text{ V}, V_{Dg} \ge 2 \text{ V}_{DS(on)}$		2000 2700			mA
		$V_{gg} = 4.5 \text{ V}, V_{Dg} \ge 2 \text{ V}_{DS(on)}$	2 V <sub>DS(on)</sub>		600		
) <sub>FS</sub>	Forward Transconductance	$V_{\text{DS}} \ge 2 V_{\text{DS(on)}}, I_{\text{D}} = 200 \text{ mA}$		100	320		mS
DYNAMIC	CHARACTERISTICS	• • • • •				•	
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$ f = 1.0 MHz			20	50	pF
C <sub>oss</sub>	Output Capacitance	f = 1.0 MHz			11	25	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				4	5	pF
SWITCHIN	G CHARACTERISTICS (Note 1)						
'on	Turn-On Time	$V_{DD} = 30 \text{ V}, \ I_{D} = 500 \text{ m A},$				10	ns
off	Turn-Off Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 25 $\Omega$				10	ns
ORAIN-SO	URCE DIODE CHARACTERISTICS ANI	D MAXIMUM RATINGS			-	-	
	Maximum Continuous Drain-Source Diode Forward Current				400	mA	
S		Maximum Pulsed Drain-Source Diode Forward Current				2000	mA
s sm	Maximum Pulsed Drain-Source Diode F	orward Current				2000	110.



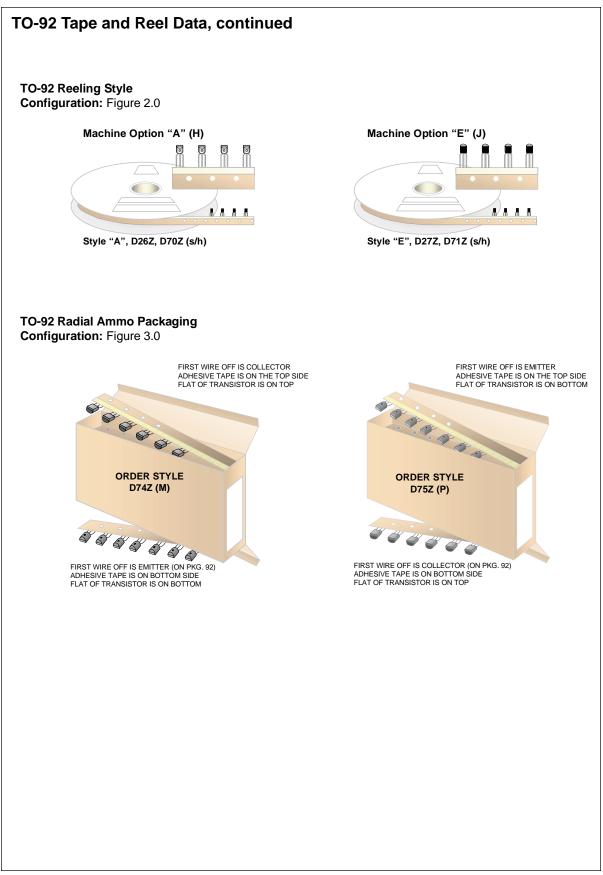
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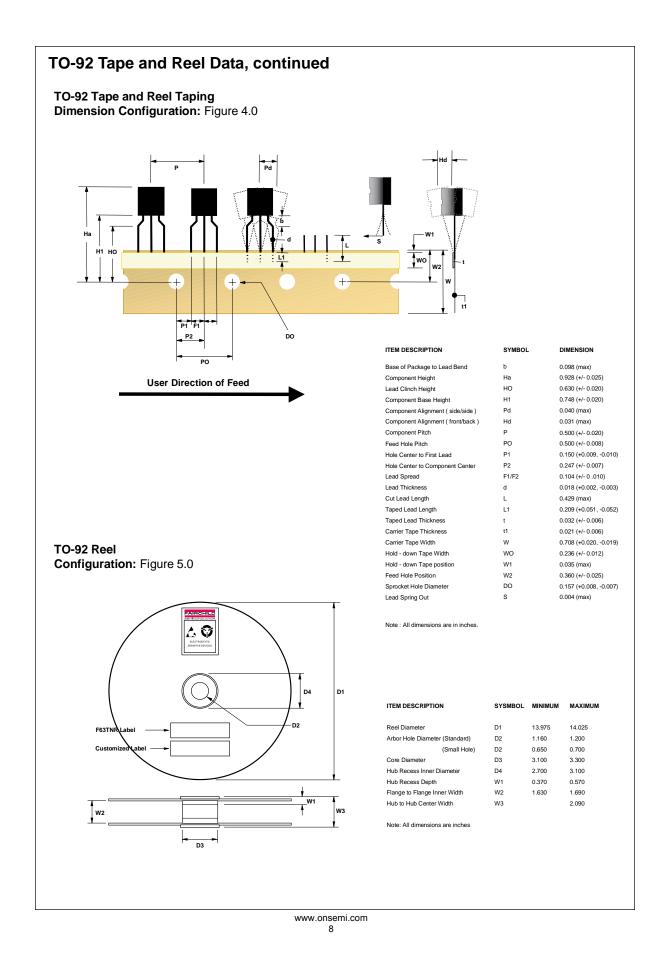


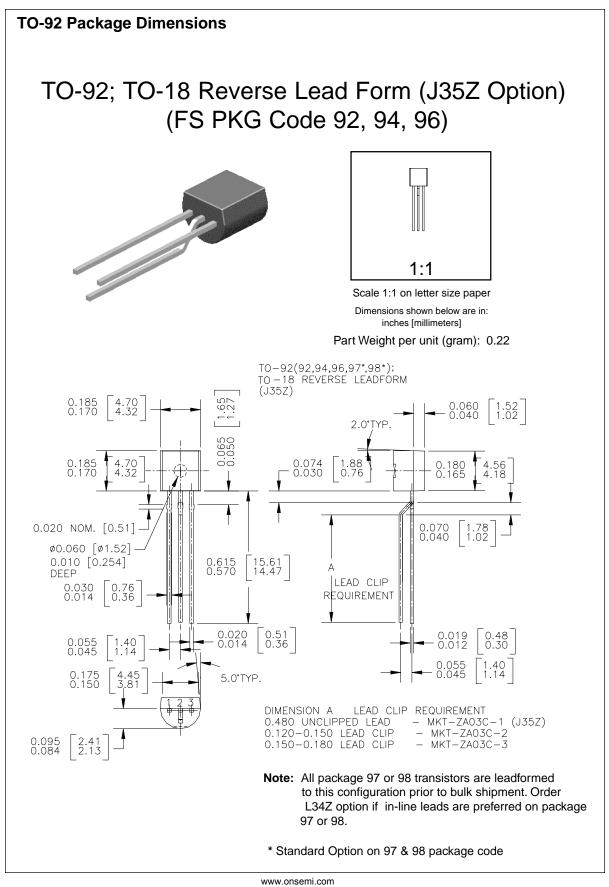




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